

MJE15032 (NPN), MJE15033 (PNP)

Complementary Silicon Plastic Power Transistors

Designed for use as high-frequency drivers in audio amplifiers.

Features

- High DC Current Gain
- High Current Gain – Bandwidth Product
- TO-220 Compact Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	250	Vdc
Collector-Base Voltage	V_{CB}	250	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current – Continuous	I_C	8.0	Adc
Collector Current – Peak	I_{CM}	16	Adc
Base Current	I_B	2.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.40	W W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2.0 0.016	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	C	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

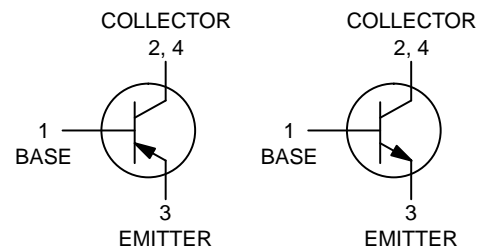


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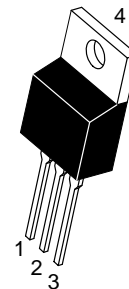
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8.0 AMPERES POWER TRANSISTORS COMPLEMENTARY SILICON 250 VOLTS, 50 WATTS

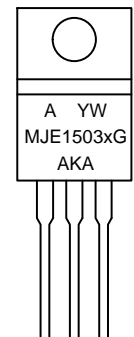
COMPLEMENTARY



MARKING DIAGRAM



**TO-220
CASE 221A
STYLE 1**



MJE1503x = Specific Device Code
x = 2 or 3
A = Assembly Location
Y = Year
W = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJE15032G	TO-220 (Pb-Free)	50 Units/Rail
MJE15033G	TO-220 (Pb-Free)	50 Units/Rail

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 1) (I _C = 10 mA, I _B = 0)	V _{CEO(sus)}	250	–	Vdc
Collector Cutoff Current (V _{CB} = 250 Vdc, I _E = 0)	I _{CBO}	–	10	μAdc
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	I _{EBO}	–	10	μAdc
ON CHARACTERISTICS (Note 1)				
DC Current Gain (I _C = 0.5 Adc, V _{CE} = 5.0 Vdc) (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc) (I _C = 2.0 Adc, V _{CE} = 5.0 Vdc)	h _{FE}	70 50 10	– – –	–
Collector–Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc)	V _{CE(sat)}	–	0.5	Vdc
Base–Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	–	1.0	Vdc
DYNAMIC CHARACTERISTICS				
Current Gain – Bandwidth Product (Note 2) (I _C = 500 mA, V _{CE} = 10 Vdc, f _{test} = 1.0 MHz)	f _T	30	–	MHz

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.
2. f_T = |h_{FE}| • f_{test}.

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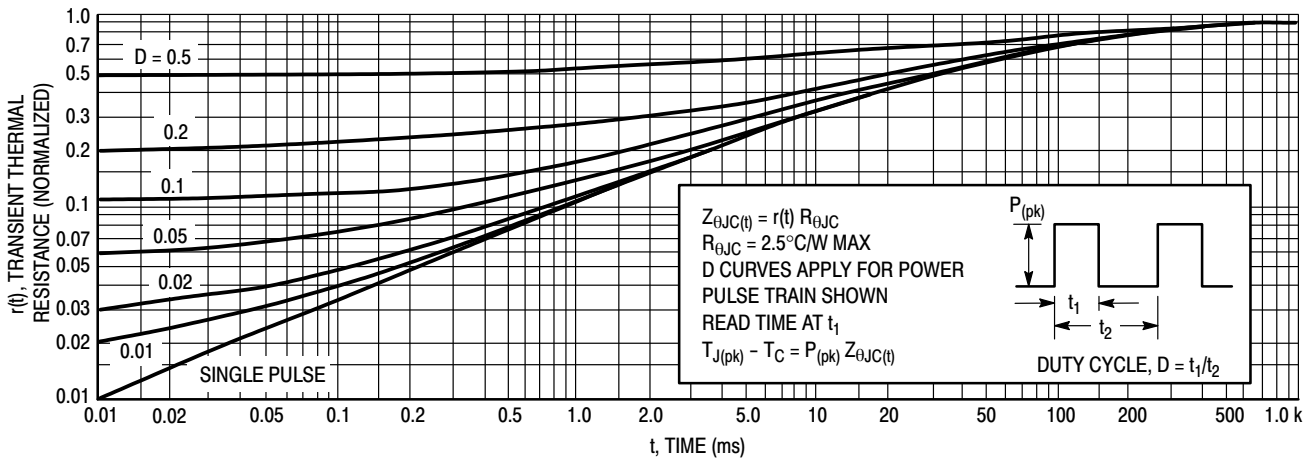


Figure 1. Thermal Response

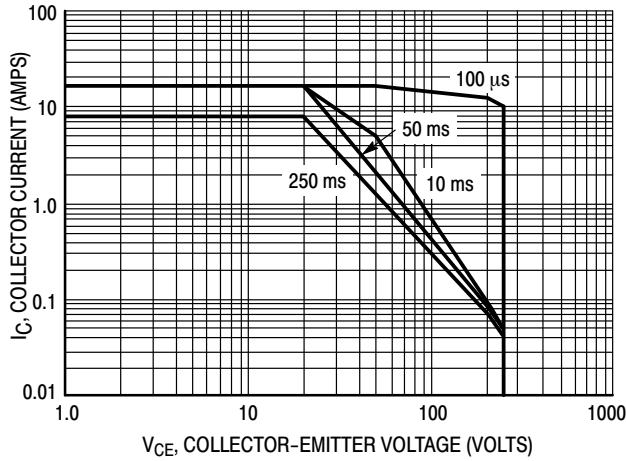


Figure 2. MJE15032 & MJE15033 Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 2 and 4 is based on $T_{J(pk)} = 150^{\circ}\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

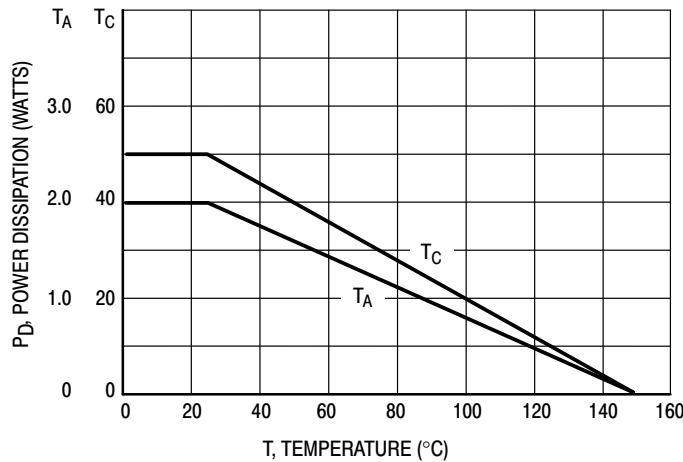


Figure 3. Power Derating

MJE15032 (NPN), MJE15033 (PNP)

NPN – MJE15032

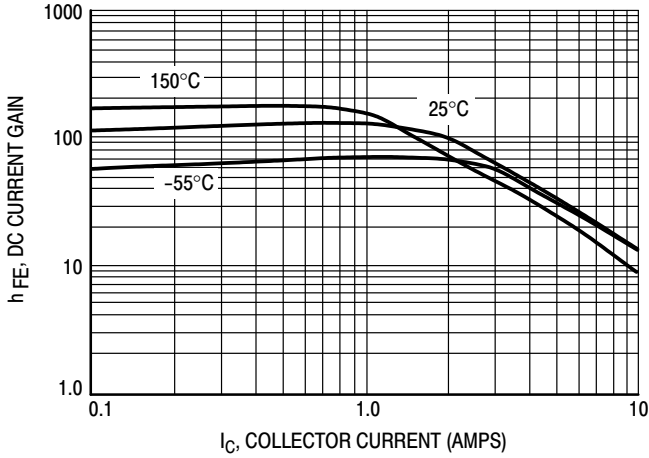


Figure 4. NPN – MJE15032
 $V_{CE} = 5\text{ V DC Current Gain}$

PNP – MJE15033

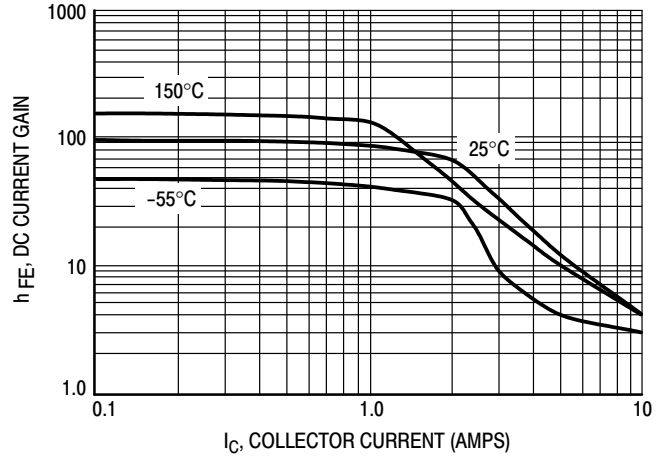


Figure 5. PNP – MJE15033
 $V_{CE} = 5\text{ V DC Current Gain}$

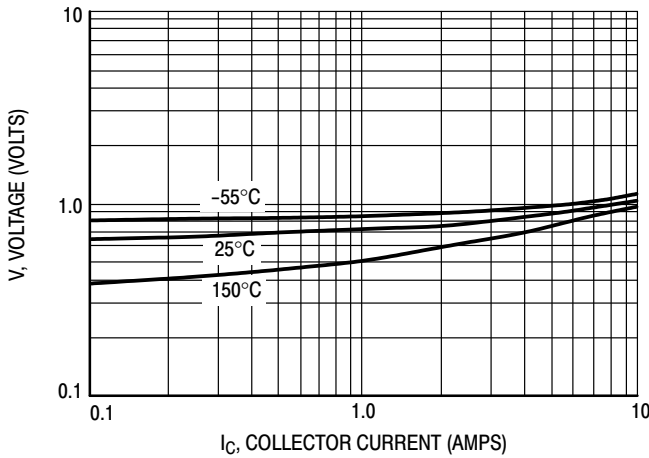


Figure 6. NPN – MJE15032
 $V_{CE} = 5\text{ V } V_{BE(on)} \text{ Curve}$

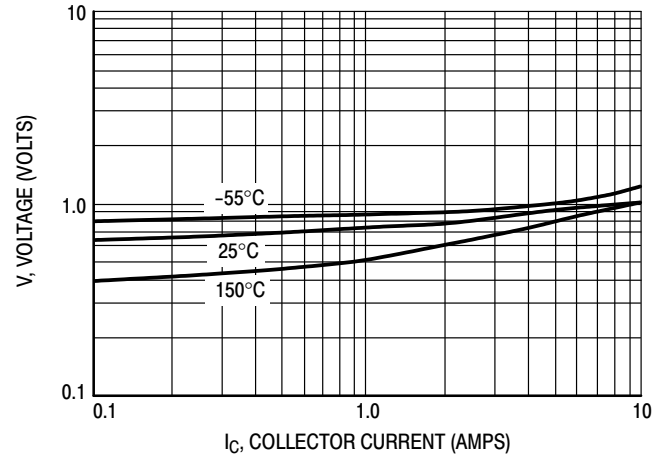


Figure 7. PNP – MJE15033
 $V_{CE} = 5\text{ V } V_{BE(on)} \text{ Curve}$

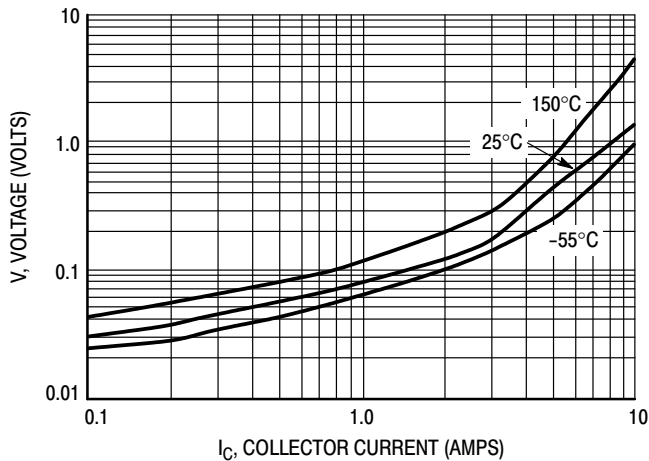


Figure 8. NPN – MJE15032
 $V_{CE(sat)} I_C/I_B = 10$

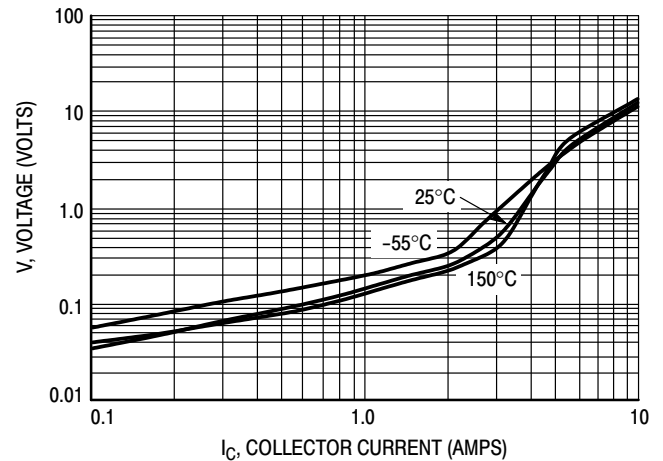


Figure 9. PNP – MJE15033
 $V_{CE(sat)} I_C/I_B = 10$

MJE15032 (NPN), MJE15033 (PNP)

NPN – MJE15032

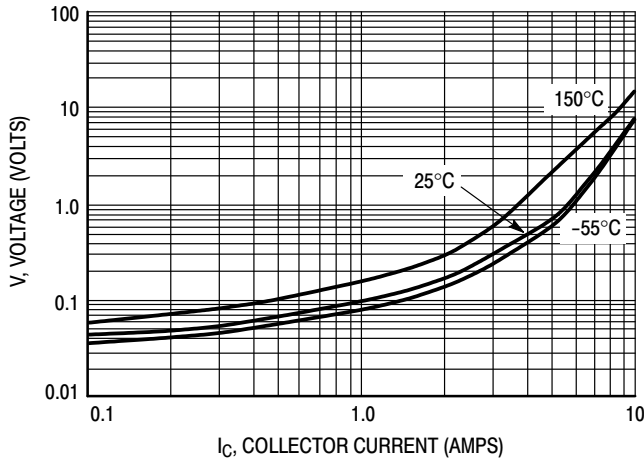


Figure 10. NPN – MJE15032
 $V_{CE(sat)} I_C/I_B = 20$

PNP – MJE15033

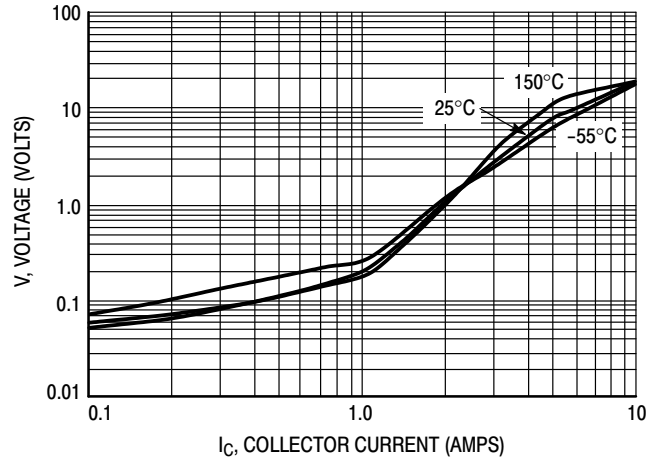


Figure 11. PNP – MJE15033
 $V_{CE(sat)} I_C/I_B = 20$

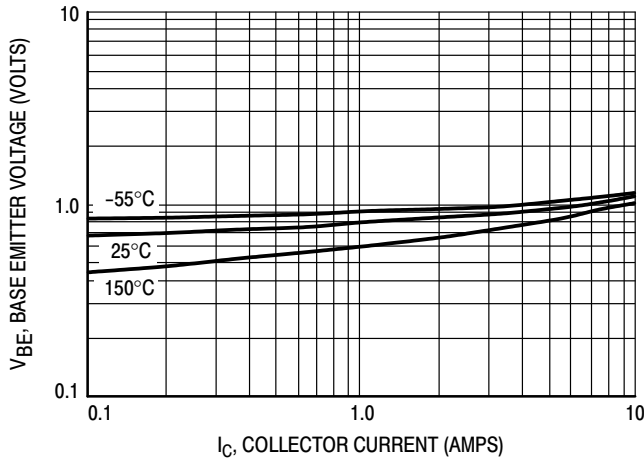


Figure 12. NPN – MJE15032
 $V_{BE(sat)} I_C/I_B = 10$

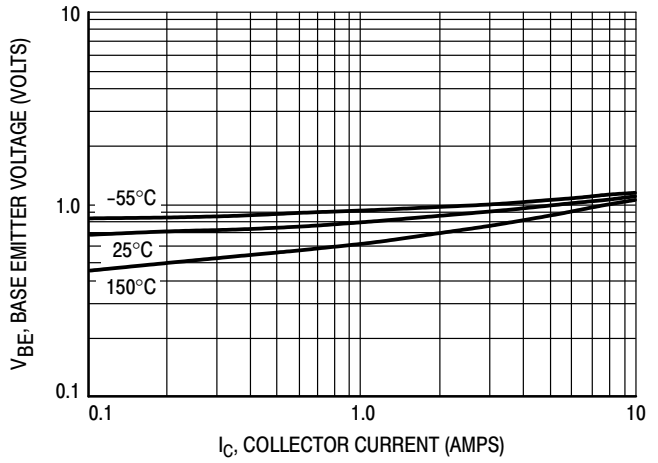
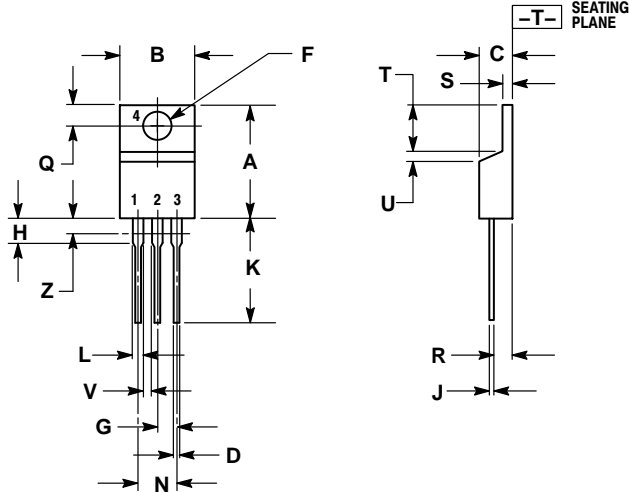


Figure 13. PNP – MJE15033
 $V_{BE(sat)} I_C/I_B = 10$

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PACKAGE DIMENSIONS

TO-220
CASE 221A-09
ISSUE AG



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:

1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

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